NSN 5962-00-232-7075

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View Online at https://aerobasegroup.com/nsn/5962-00-232-7075
Body Length:
Between 0.755 inches and 0.785 inches
Body Width:
Between 0.265 inches and 0.291 inches
Body Height:
Between 0.159 inches and 0.199 inches
Operating Tempurature Range:
+0.0/+75.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Type angyk3v coordinate data terminal
Features Provided:
Hermetically sealed and monolithic and positive outputs and bipolar and programmable and programmed and w/buffered output and
w/decoded output and w/enable and w/open collector
Inclosure Material:
Ceramic and glass
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
10 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
-1.5 volts power source and 5.5 volts power source
Time Rating Per Chacteristic:
60.00 nanoseconds propagation delay time, low to high level output
Memory Device Type:
Rom
Memory Capacity:
Unknown
Test Data Document:
08241-1745-2210 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing
etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)
Terminal Type And Quantity:
16 printed circuit
Shelf Life:
N/a

Demilitarization: Yes - demil/mli

Unit Of Measure:

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